

# Solar cells in radiation environments Application of SPENVIS for solar cell performance prediction

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- Are radiation studies a worthwhile investment ?
- Improving the cost effectiveness of radiation prediction
  - JPL 'Equivalent fluence model' (EQFLUX in SPENVIS)
  - many organisations and companies in Europe and elsewhere use this method via SPENVIS
  - *it has worked well historically and is available to the whole community*
  - Requires lots of reference data for every new cell type
  - NRL Displacement damage dose concept
  - A potential alternative to EQFLUX that requires less test data
  - see presentation by Scott Messenger
  - Theoretical model based on introduction of recombination centers in the solar cell
  - A theoretical model, hence potentially several possible applications inside or outside SPENVIS
  - see presentation by Jacques Bourgoin

**Motivation - Economics for a 10kW Solar Array** 



- <u>Relative Costs (rough numbers...)</u>
- Cost to launch a 10kW solar array based on <u>mass only</u>
  - Say €4M (@ €30k/kg)
  - Note that mass is not necessarily critical if the mass of the satellite is compatible with the capacity of a designated launcher, but this is anyway a useful number...
- Cost of a 5% power margin based on only this number
  - Around €200k
- Cost of a radiation campaign on a new cell design
  - Potentially several €100k (cost of samples, radiation, measurements...)
  - This is equivalent to the profit on sales of a lot of solar cells.... !!
  - Cost of qualification is significant, but still a good investment
- <u>Conclusions</u>
- Extra power margin is very expensive !!
- We would like to reduce the cost of ground testing, but <u>NOT</u> at the expense of the accuracy of power prediction
- A radiation study costing up to several €100k which improves 'end of life' power prediction is likely to pay for itself very quickly....
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- Most solar cell degradation in space is mostly caused by displacement damage
- Atomic displacement introduces 'recombination centers' which reduce the probability that an electron will contribute to the solar cell current
- Space solar cells are protected by a coverglass to reduce the radiation dose (mostly by slowing down the whole proton spectrum and cutting out low energy protons)
- For this reason, we tend to perform ground tests on unprotected solar cells with protons and electrons in the range 0.1MeV to 10MeV

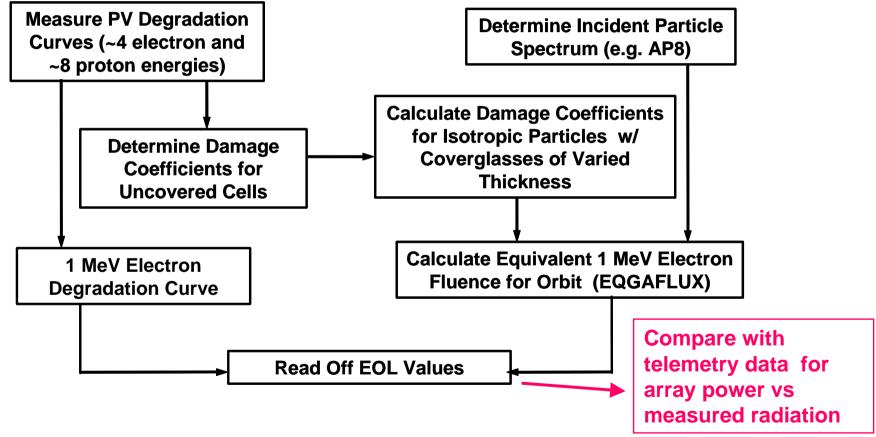
### Implementation in SPENVIS (using EQFLUX)

	<u>SPENVIS Project: GEO</u> Model packages	Output Help
1 2 3 3 See also development of NIEL model in MULASSIS	Coordinate generatorsRadiation sources and effectsRadiation sourcesTrapped proton and electron fluxesTrapped proton flux anisotropySolar proton fluencesRadiation dosesDamage equivalent fluences for solar cellsDose models for simple geometriesSectoring analysis for more complex geometriesSingle event effectsIon energy and LET spectraSingle event upset ratesSingle event upset ratesMagnetic fieldMagnetic fieldData base queriesLiscellaneousECSS Space Environment Standard	SPENVIS is an efficient forum for a new model within the solar power community !



### **JPL Equivalent Fluence Method**

Improvement of any step makes a difference to the end result....



• From S.R.Messenger et al, Progress in Photovoltaics 9, 103 (2001) Spenvis Workshop - Leuven 2005

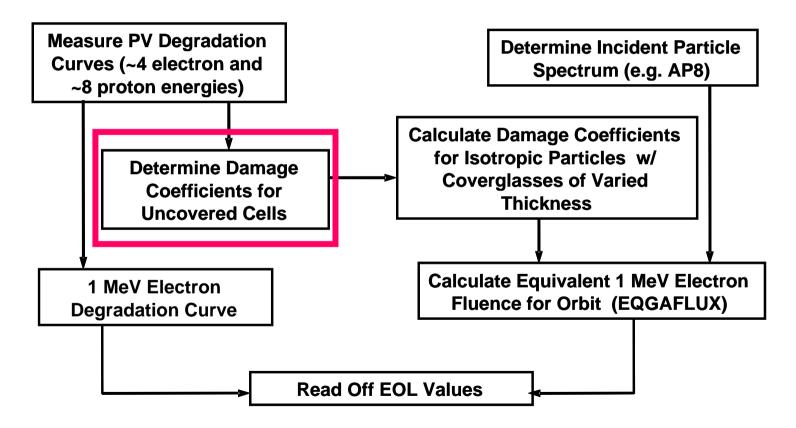


- How can we make 'end of life' performance prediction more cost effective ?
  - Improve knowledge of the environment
  - Understand and model the interactions between the environment and the device
  - Acquire appropriate ground test data
  - Compare predictions with in-flight data from solar arrays and radiation monitors

eesa  $P/P_0 = 1 - A \log(1 + \Phi/B)$ : See presentation by Jacques Bourgoin 1.0 GaAs/Ge 1 Sun, AMO 0.9 Normalized Maximum Power 25°C 0.8 0.7 0.6 Protons 0.5 9.5 MeV 1MeV electron 3 MeV 0.4 reference curve MeV Electrons 0.5 MeV 0.3 0.3 MeV We define an 6 MeV 0.2 MeV MeV 0.2 'equivalent 0.1 MeV 4 MeV 0.05 MeV fluence' for a 12 MeV 0.1 mission 0.0 10<sup>10</sup> 10<sup>14</sup> 10<sup>15</sup> 10<sup>16</sup> 10<sup>8</sup> 10<sup>9</sup> 10<sup>11</sup> 10<sup>12</sup> 10<sup>13</sup> 10<sup>17</sup> Particle Fluence (cm<sup>-2</sup>)

• From S.R.Messenger et al, Progress in Photovoltaics 9, 103 (2001) Spenvis Workshop - Leuven 2005

### **JPL Equivalent Fluence Method**

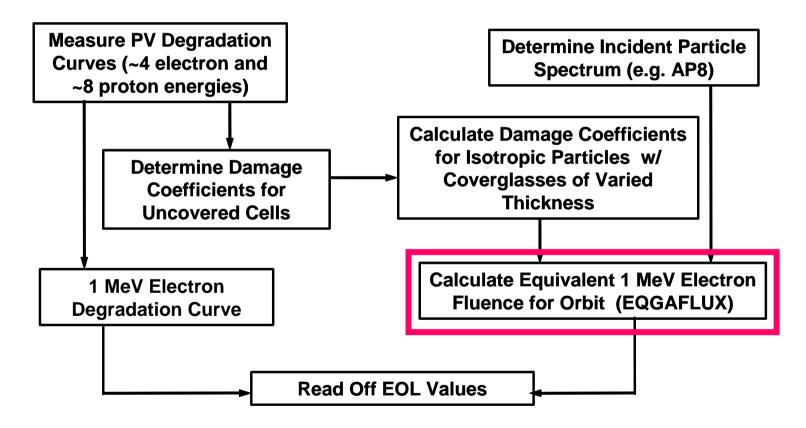


• From S.R.Messenger et al, Progress in Photovoltaics 9, 103 (2001) Spenvis Workshop - Leuven 2005

#### **Difficulties with application to Multi-Junction Cells – Example 1.**

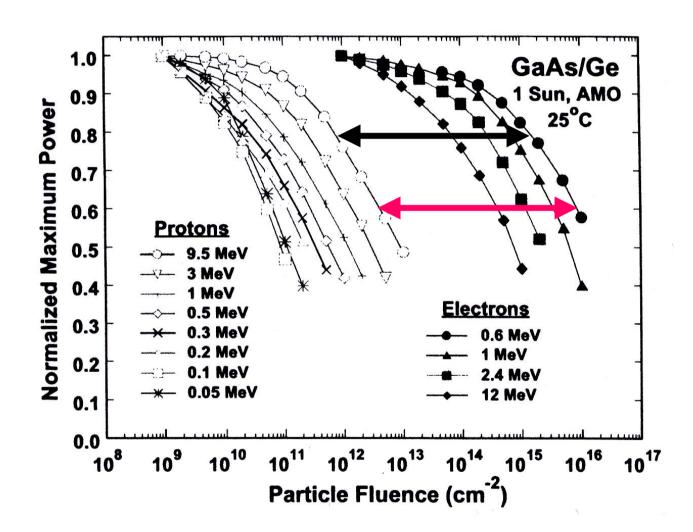
1.00E+00 AR coating GalnP GaAs Ge 1.00E-01 50keV protons stop in the top cell vacancies per proton per angstrom 1.00E-02 50keV RDC is 1.00E-03 correct only IF top cell is current limiting 1.00E-04 1.00E-05 -50keV 100keV 400keV 1.00E-06 1.00E-02 1.00E-01 1.00E+00 1.00E+01 depth (microns)

### **JPL Equivalent Fluence Method**



• From S.R.Messenger et al, Progress in Photovoltaics 9, 103 (2001) Spenvis Workshop - Leuven 2005

#### **Establishment of Relative Damage Coefficients**



RDC's are defined for a given remaining factor

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All curves need to be parallel to give accurate results

Care needs to be taken for:

**1. Triple-junction cells** 

2. Low energy protons

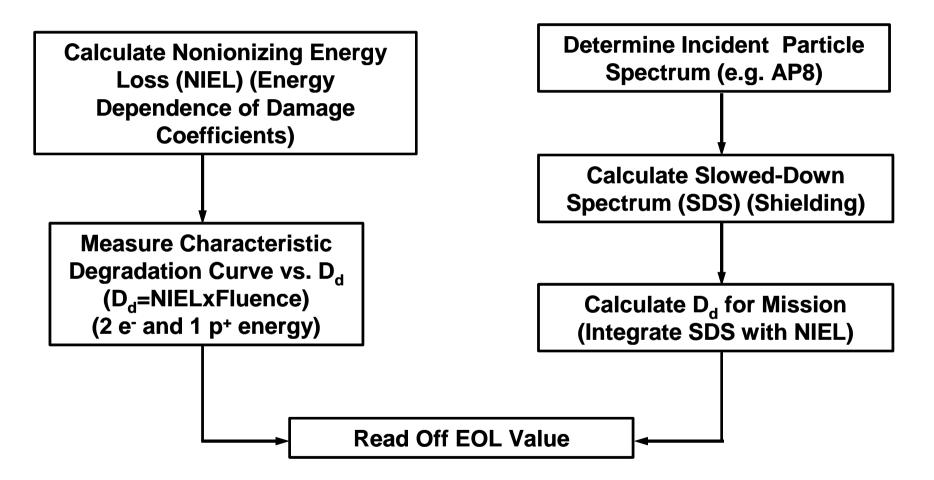
Spenvis Workshop - Leuven From S.R. Messenger et al, Progress in Photovoltaics 9, 103 (2001)



- Cells are electrically connected in series strings
  - How uniform is cell degradation and how does this affect the string performance ?
- Array level testing calibration uncertainties
- How accurate are corrections for albedo, temperature, incidence angle etc ?
- How do we combine all this information in a model of the power system ?
- What telemetry data is available ?
- There are few available published comparisons between cell, ground level array testing and flight data for triple junction cells

### **NRL Displacement Damage Dose Method**

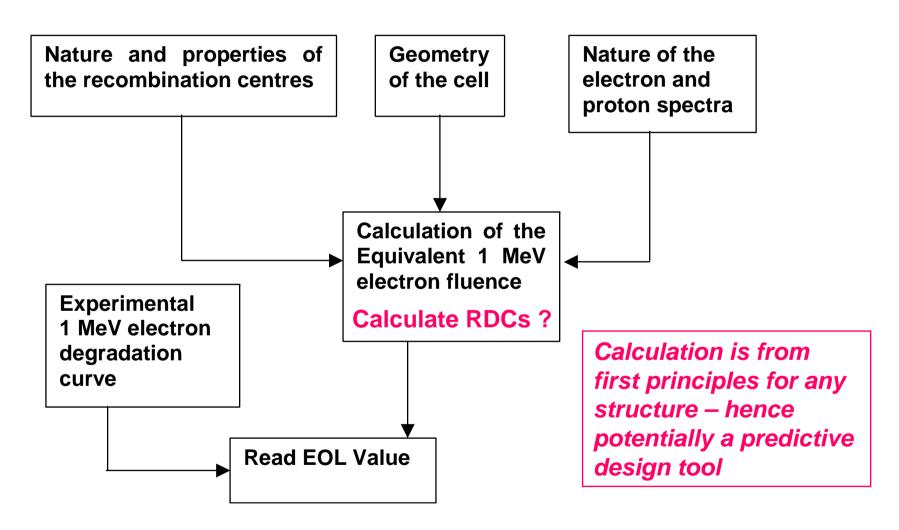
Potentially similar accuracy to EQFLUX from less ground test data



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### Fundamental Model – may be complementary to EQFLUX ?



## Preliminary results generated using 'MATHCAD' implementation

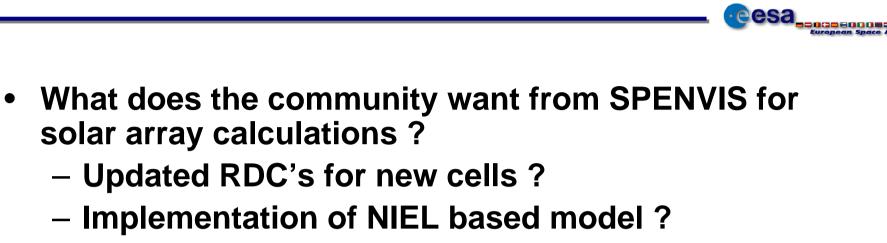
1.1 1 9 0.9 8 0.8 Relative damage coefficients 0.7 0.7 0.6 0.5 0.4 BOL match spectrolab 3J BOL match spectrolab 3J EOL 0.3 EOL match - -EOL match 0.2 1 0 0.1 2 0 4 6 8 10 12 0 energy (MeV) 1.E+13 1.E+14 1.E+15 1.E+16 1MeV electron fluence

#### From N. de Angelis et al., Proc. IEEE PV specialists conf., 2005

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- EQFLUX is the 'default' reference
  - We need to show that any new model can achieve at least an equivalent level of accuracy to EQFLUX
  - We need to update the solar cell databases in EQFLUX both to use it accurately and to facilitate comparison
- Comparison with EQFLUX must be easy
- Validation is a critical step but published flight data for multi-junction cells is scarce
- Making SPENVIS an efficient forum for these models helps to facilitate validation / comparison and reduce duplication of effort within the community



- This will help us to focus resources effectively
- How to validate a new model ?
- How to apply a fundamental model ?
  - Calculate and upload RDC's into EQFLUX ?
  - A design tool complementary to EQFLUX or a completely new application ?
  - How to deal with confidentiality issues concerning cell structure ?